## NSN 5961-01-097-4349

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-097-4349 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.713 inches **Overall Diameter:** Between 0.065 inches and 0.085 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 2.50 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 turret **Specification Data:** 80131-release 6377 professional/industrial association standard Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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